

Synthesis of visible and near-infrared light responded $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ for efficient degradation of high concentration rhodamine B

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Visible and near-infrared light responded $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ nanosheets was synthesised via a simple hydrothermal method. Rhodamine B was adopted to evaluate the degradation efficiency of the as-prepared samples. Experimental results showed that the doping content of Bi^{3+} could obviously affect the degradation efficiency of SnS_2 . It was first increased and then decreased with increasing the Bi^{3+} content under the visible light irradiation. When the mole fraction of doping Bi^{3+} was 5%, the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ with a bandgap of 0.38 eV had the highest degradation efficiency of 95.9% in 120 min. Moreover, the as-prepared composites possessed more effective electron-hole pair separation than that of pure SnS_2 . In addition, a possible degradation mechanism of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ was proposed.

1. Introduction: Recently, water pollution has become an emergent problem worldwide. Semiconductor photocatalysts have gained much attention due to their potential applications in solving water pollution [1, 2]. However, the traditional semiconductors, such as TiO_2 [3] and CuO [4], are limited by their wide bandgap energy (>3.2 eV), only sensitive to ultraviolet light, unable to make good use of the sunlight. Recently, much research has been devoted to the exploration of metal sulphides, such as Bi_2S_3 [5], ZnIn_2S_4 [6], SnS_2 [7], as their bandgap energy is lower than 2.9 eV. Among these photocatalysts, SnS_2 possesses great potential because of its low cost, low toxicity, wide range of response in visible and near-infrared regions. However, the limited photocatalytic activity restrains its further development and application. Doping metal ions, such as Bi^{3+} , has been proven to be an effective method to enhance the light absorption and photocatalytic properties of semiconductors [8, 9].

In this work, $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ was synthesised via a hydrothermal process. Experimental results showed that doping Bi^{3+} could improve the degradation efficiency of pure SnS_2 for rhodamine B (RhB) solution. It might provide reference values for visible and near-infrared light responded photocatalysis.

2. Experimental section: In a typical procedure, 10 mmol $\text{SnCl}_4 \cdot 5\text{H}_2\text{O}$ (3.5 g) and 66.6 mmol thioacetamide (5.0 g) were dissolved in 70 ml deionised water. Then, a certain amount of $\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$ [0.1, 0.3, 0.5 and 0.7 mmol, and the molar ratio of $\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$ to $\text{SnCl}_4 \cdot 5\text{H}_2\text{O}$ was 0.01, 0.03, 0.05 and 0.07] was added into the above solution and ultrasonicated for 0.5 h to form suspension. Subsequently, the obtained suspension was transferred into a 100 ml Teflon-lined autoclave and heated at 180°C for 10 h. Finally, the samples were cooled to room temperature, washed with deionised water and ethanol for several times, and dried in a drum wind drying oven at 60°C for 8 h before their further characterisations. The as-prepared samples were defined as $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ ($x=0.01, 0.03, 0.05$ and 0.07 , respectively). For comparison, pure SnS_2 was prepared via the same method without using any $\text{Bi}(\text{NO}_3)_3 \cdot 5\text{H}_2\text{O}$.

The photocatalytic activity of the as-prepared samples was evaluated by degradation of RhB. A 300 W Xe lamp was used as the light source equipped with a cutoff filter ($\lambda > 420$ nm). In a

typical measurement, 50 mg photocatalyst was mixed with 150 ml high concentration (40 mg l^{-1}) of RhB solution. Before the illumination, the suspension solution was stirred in the dark for 1 h to reach the equilibrium of absorption-desorption. The absorbance of RhB solution was measured by a visible spectrophotometer.

3. Results and discussion: Fig. 1a shows XRD patterns of pure SnS_2 and the as-synthesised $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with doping various contents of Bi^{3+} . It can be seen that the diffraction peaks of pure SnS_2 were at $2\theta = 15.05^\circ, 28.30^\circ, 32.21^\circ, 50.11^\circ$ and 52.62° , indexed to (001), (100), (011), (110), (111) according to PDF# 83-1705. No obvious peaks of any other phases or impurities, such as Bi_2S_3 , were observed after doping Bi^{3+} . This result indicated that the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ possessed a single phase and high purity. Moreover, it can be seen that the width of all the diffraction peaks was broadened with increasing the content of Bi^{3+} . This was caused by the decreased crystallinity. It might be that more and more Sn^{4+} were replaced by Bi^{3+} with increasing the Bi^{3+} content, and a large number of defects were introduced into the lattice. Moreover, the lattice distortion and strain were significantly intensified, might disturb the crystallisation and cause to a decreased crystallinity. In Fig. 1b, the magnified view of (001) crystallographic planes are displayed, which show the peaks tend to shift to lower 2θ angles [15.05° for pure SnS_2 and $15.04, 15.03, 15.01, 14.95^\circ$ for the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ ($x=0.01, 0.03, 0.05$ and 0.07)] with increasing the doping Bi^{3+} content. These results illustrated that Sn^{4+} were successfully replaced by Bi^{3+} . The schematic diagram was shown in Fig. 2.

Fig. 3a shows UV-Vis diffuse reflectance spectroscopy (DRS) of pure SnS_2 and the as-synthesised $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with doping various contents of Bi^{3+} from 300 to 1000 nm. It can be seen that all samples possessed obvious absorption in the visible and near-infrared range. Moreover, all the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with doping various Bi^{3+} contents exhibited an enhanced light absorption compared with that of pure SnS_2 . The similar phenomenon could also be found in $\text{Sn}_{1-x}\text{Ag}_x\text{S}_2$ with doping various Ag^+ contents [10]. This was in favour of the degradation of RhB solution. As shown in Fig. 3b, it can be observed that all the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with doping various contents of Bi^{3+} showed smaller

bandgap energy than that of pure SnS_2 . When the mole fraction of doping Bi^{3+} was 5%, the bandgap energy reached the minimum value of 0.38 eV. This was much narrower than 1.58 eV of pure SnS_2 , indicating that slight Bi^{3+} could effectively narrow the bandgap of pure SnS_2 .

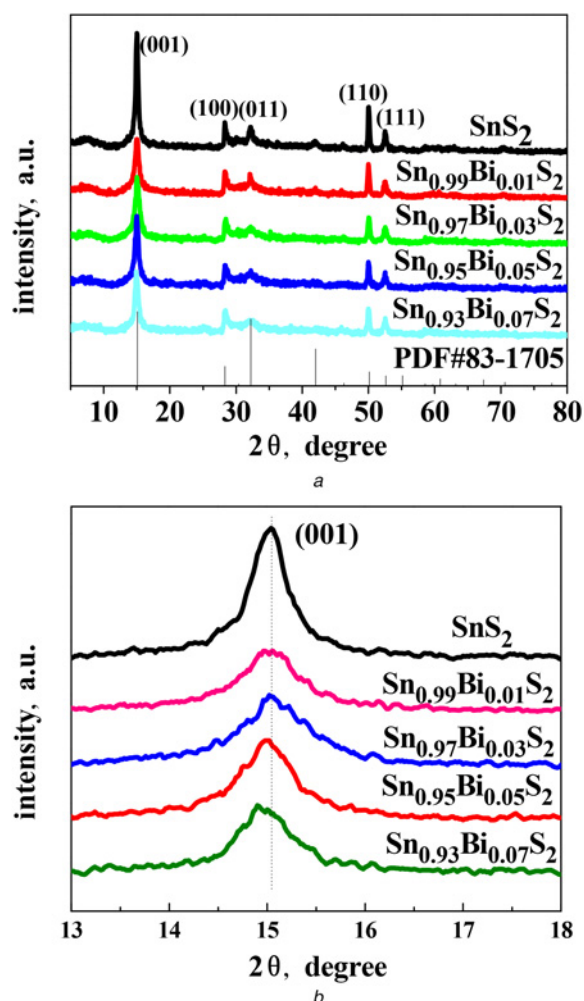


Fig. 1 XRD patterns and (001) peaks of pure SnS_2 and the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$
a XRD patterns of pure SnS_2 and the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with doping various contents of Bi^{3+}
b (001) peaks of pure SnS_2 and the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with doping various contents of Bi^{3+}

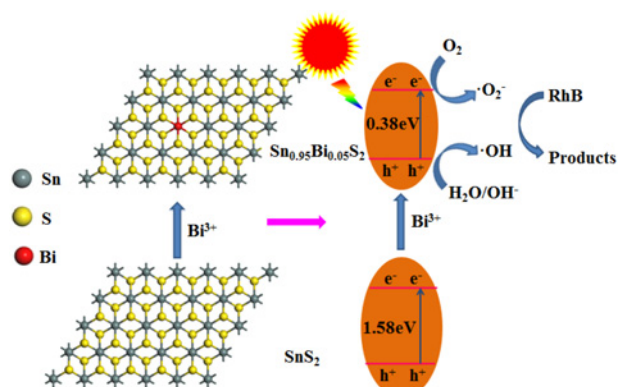


Fig. 2 Possible degradation mechanism of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ nanosheets

The degradation efficiency of the as-prepared samples was evaluated by degradation of high concentration (40 mg l^{-1}) of RhB under the visible-light irradiation. As is shown in Fig. 4a, it can be seen the adsorption capacity gradually increased with increasing the doping content of Bi^{3+} . Moreover, doping Bi^{3+} could improve the degradation efficiency of pure SnS_2 . The overall degradation efficiency of the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ was increased and then decreased with increasing the doping content. When the mole fraction of doping Bi^{3+} was 5%, the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ had the highest degradation efficiency of 95.9% in 120 min. In Fig. 4b, the photocatalytic efficiency of the as-prepared samples under the visible light irradiation is shown. Similar results were obtained as in Fig. 4a. When the mole fraction of doping Bi^{3+} was 5%, it exhibited the highest photocatalytic efficiency of 80.27% in 120 min. However, when the mole fraction of doping Bi^{3+} increased to 7%, it was not further increased. This might be because that lattice disorder was enhanced with increasing the doping Bi^{3+} content. Excessive Bi^{3+} could not enter the lattice or further narrow the bandgap.

In Fig. 5, it shows the elements composition and chemical states of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$. Fig. 5a revealed only Sn, S and Bi peaks existed in the survey spectra of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$, besides C and O from surface contamination. It illustrated that high purity of the as-prepared sample was obtained. As is shown in Fig. 5b, there were two peaks of Sn 3d located at 486.9 and 495.3 eV, which were attributed to the $\text{Sn } 3d_{5/2}$ and $\text{Sn } 3d_{3/2}$

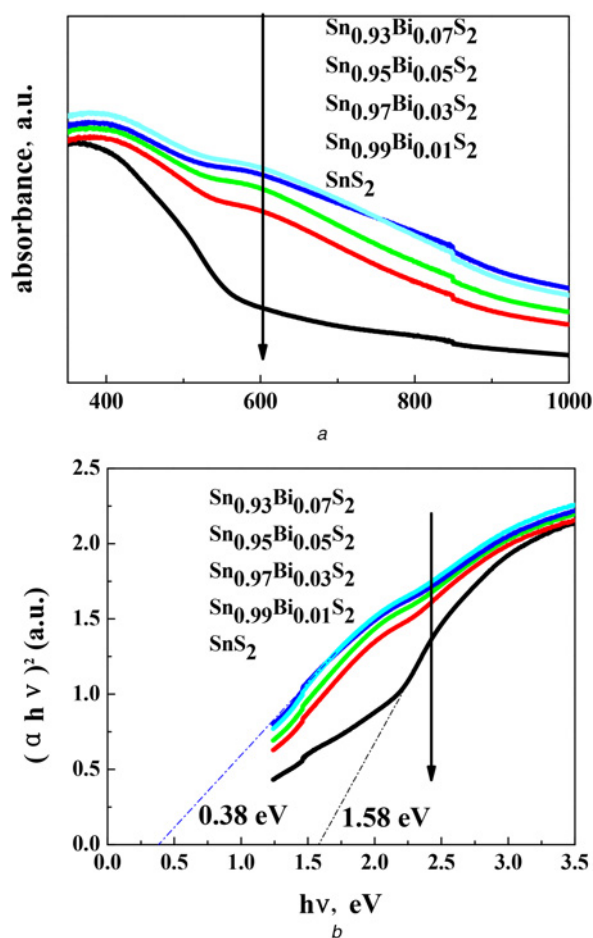


Fig. 3 UV-Vis DRS and calculation of the bandgap energy of pure SnS_2 and the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$
a UV-Vis DRS of pure SnS_2 and the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with doping various contents of Bi^{3+}
b Calculation of the bandgap energy of pure SnS_2 and the as-prepared $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with doping various contents of Bi^{3+} based on the $(\alpha h\nu)^2 - h\nu$ curve

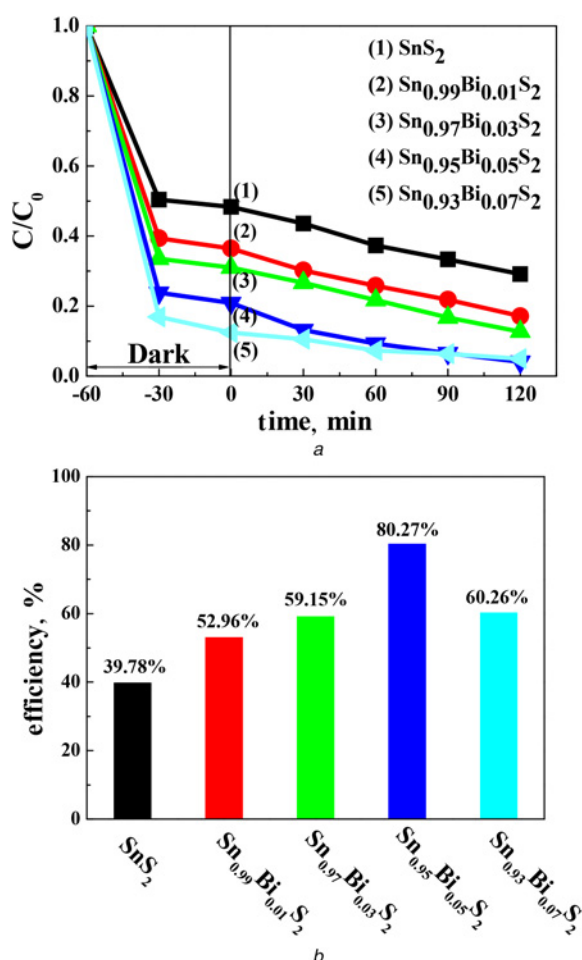


Fig. 4 Time profile and photocatalytic efficiency of the samples
 a Time profile of C/C_0 of RhB
 b Photocatalytic efficiency of the samples under the visible light irradiation

binding energies, respectively. It also indicated that Sn was 4+ state [11]. Fig. 5c shows the X-ray photoelectron spectroscopy (XPS) spectra of S 2p and Bi 4f. The strong peak at 161.9 eV, attributed to S 2p binding energy, was assigned to S^{2-} . Two weak peaks at 158.3 and 163.8 eV correspond to the binding energies of Bi 4f_{7/2} and Bi 4f_{5/2}, respectively, indicating Bi was 3+ state [12]. This result demonstrated the formation of Bi^{3+} and was in line with the result of XRD.

Transmission electron microscopy (TEM) is usually adopted to observe the morphology of the as-prepared products [13]. In Fig. 6a, it can be seen that most pure SnS_2 particles were hexagonal nanosheets with the size of 30–50 nm, as is shown as the white arrows. Moreover, in Fig. 6b, it shows that the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ had similar morphology with pure SnS_2 . This result indicated that doping Bi^{3+} could not obviously change the morphology of pure SnS_2 . Fig. 6c shows the high-resolution TEM (HRTEM) image of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$. It can be seen that the lattice fringe spacing was 0.278 nm, corresponding to the (011) plane of $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$.

Electrochemical impedance spectroscopy was employed to prove the charge transfer resistance and the separation efficiency between the photogenerated electrons and holes. EIS of pure SnS_2 and the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ is shown in Fig. 7. It can be seen that the arc radius of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ was significantly smaller than that of pure SnS_2 , indicating that the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ possessed lower charge transfer resistance than that of pure SnS_2 . This could further support that the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ had more effective electron–hole pair separation and higher degradation efficiency than that of pure SnS_2 .

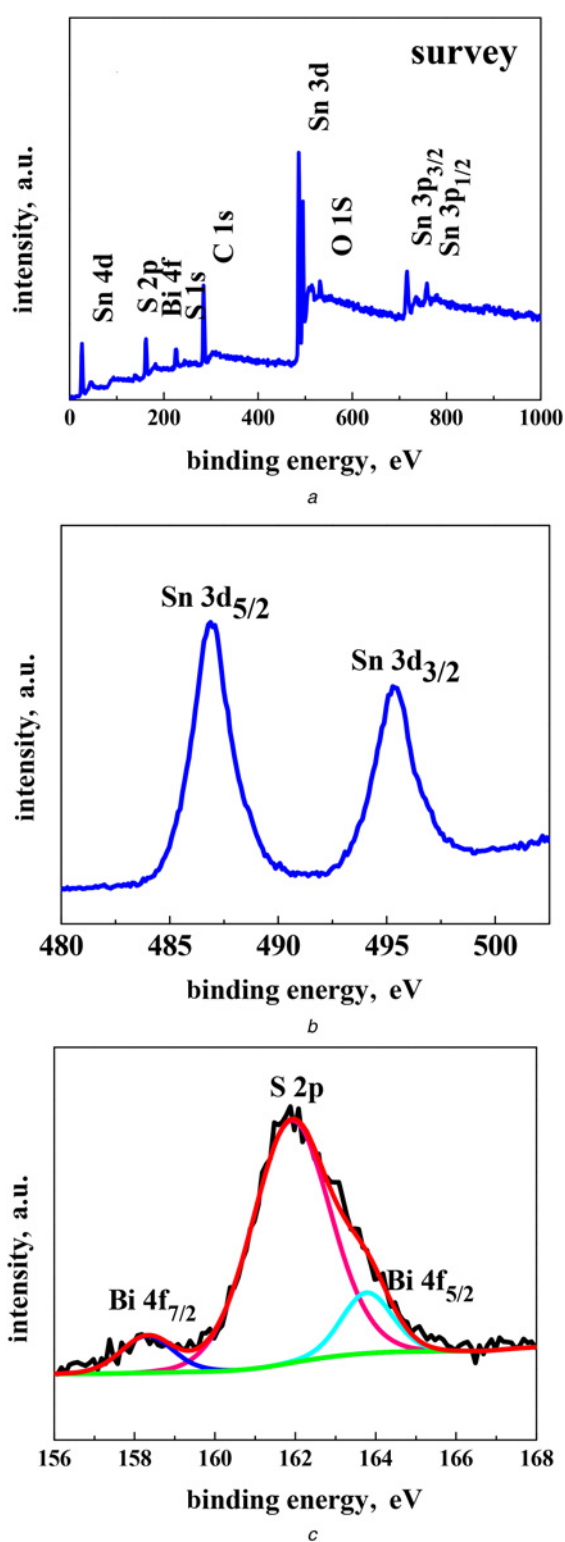


Fig. 5 XPS spectra of
 a Survey spectra
 b Sn 3d
 c Bi 4f and S 2p for the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$

The active species trapping experiments for degradation of RhB over the as-obtained $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ were carried out to analyse the photocatalytic mechanism. The ethylenediamine tetraacetic acid (EDTA), benzoquinone (BQ) and t-butanol (TBA) were separately used as h^+ , O_2^- and $\cdot\text{OH}$ scavengers, respectively [14]. The results are shown in Fig. 8. It can be observed that after using the scavengers, the photocatalytic activity was suppressed. It is worth

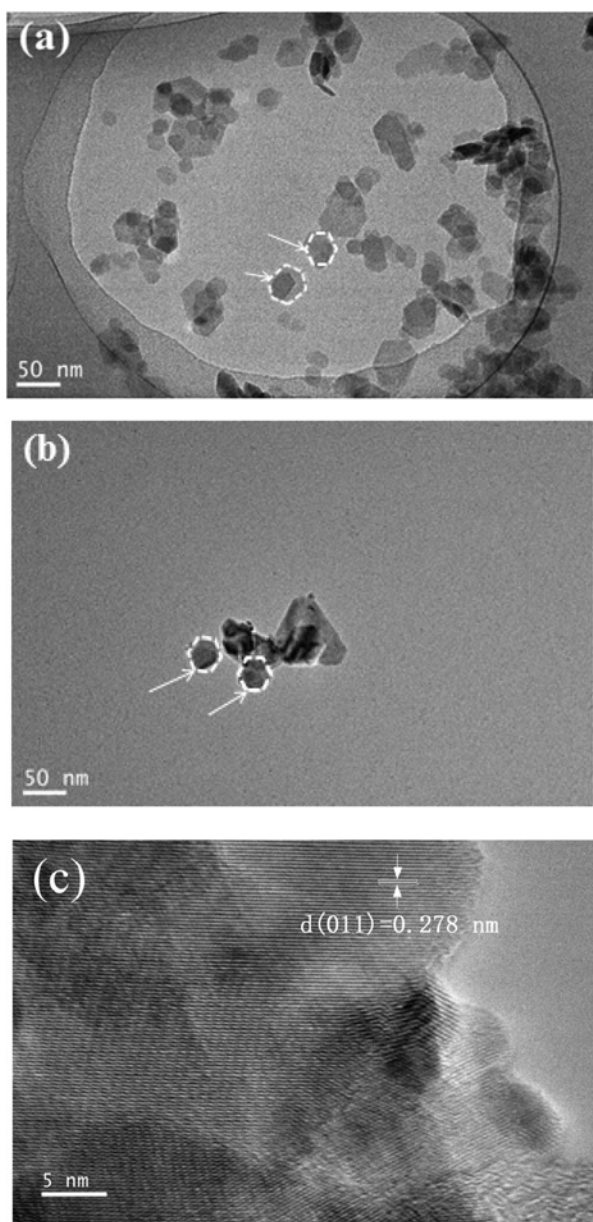


Fig. 6 TEM images of
a Pure SnS_2
b As-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$
c HRTEM images of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$

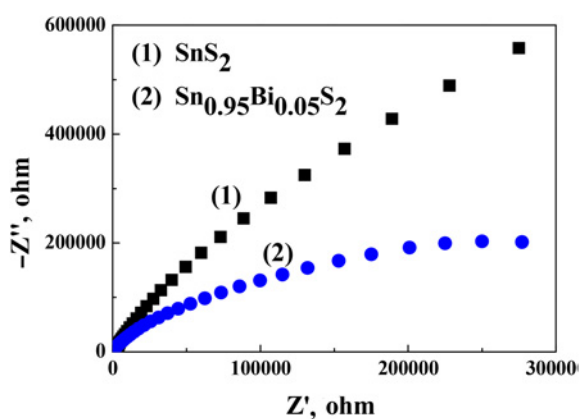


Fig. 7 EIS Nyquist plot of pure SnS_2 and the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$

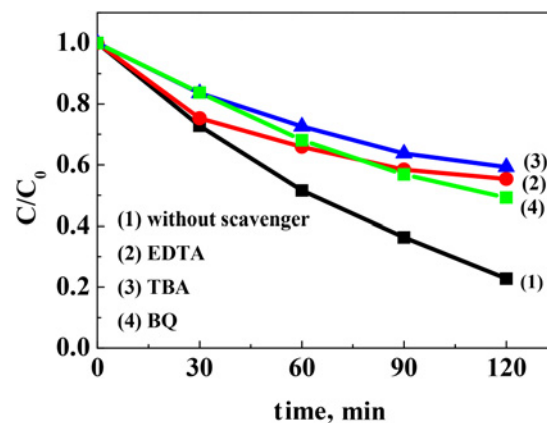


Fig. 8 Photocatalytic degradation curves of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$: (1) without using any scavenger; (2) with using EDTA; (3) with using TBA; (4) with using BQ

noting that the scavenging effect of TBA was the most obvious, indicating that $\cdot\text{OH}$ was the main active species and played the main role during the photocatalytic processes.

Based on the above results, a possible degradation mechanism of the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ is proposed in Fig. 2. It can be seen that the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ could be excited more easily by Xe light to produce photogenerated electrons and holes due to very narrow bandgap. Moreover, the photogenerated electrons could absorb O_2 to generate O_2^- ; meanwhile, the holes oxidised H_2O or OH^- into $\cdot\text{OH}$. Finally, RhB was oxidised to degrade.

4. Conclusion: In summary, visible and near-infrared light responded $\text{Sn}_{1-x}\text{Bi}_x\text{S}_2$ with high purity had been fabricated through a hydrothermal method. Experimental results showed that the doping content of Bi^{3+} greatly influenced the degradation efficiency of as-prepared samples. It was first increased and then decreased with increasing the doping content of Bi^{3+} . When the mole fraction of doping Bi^{3+} was 5%, the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ nanosheets had the highest degradation efficiency of 95.9% in 120 min and the narrowest bandgap energy of 0.38 eV. Moreover, the as-prepared $\text{Sn}_{0.95}\text{Bi}_{0.05}\text{S}_2$ possessed more effective electron-hole pair separation than that of pure SnS_2 . In addition, $\cdot\text{OH}$ played the main role during the degradation. This work indicated that doping Bi^{3+} was one of effective methods to improve the photocatalytic degradation efficiency, narrow the bad gap energy of pure SnS_2 as well as promote its application in photocatalytic degradation of organic dye.

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6 References

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